



△×				APPROVED	CHECKED	MATERIAL 材料	-	CHAMFER 一般面取	-	QUANTITY 個数	
△×				T. A.	T. A.	TREATMENT 処理	-	FINISHING 仕上	-	-	
△×						TREATMENT CONTACT 処理接点	-	DECENTRATION 偏芯	-		
△×				DESIGNED	DRAWN	OVER 250 UP TO 1000	±0.3 ±0.5 ±1.0 ±0.2	ANGLE 角度	METHOD 図法	REMARK 適用 (機種名)	
△×				T. A.	T. S.	OVER 63 UP TO 250	±0.2 ±0.3 ±0.6 ±0.15	UNIT (mm)	-	VS-0818H/3CMOS	
△×						OVER 16 UP TO 63	±0.1 ±0.2 ±0.4 ±0.1				SCALE
△×						OVER 0 UP TO 16	±0.05 ±0.1 ±0.2 ±0.1	DATE	17.09.12	DRAW NO.	01D S V 0 1 5 9 A 1
NO. × 箇所	REVISION 訂正事項	DATE	NAME	TOLERANCES A B C S							